May 2002 Revised June 2005

FSTU16862 20-Bit Bus Switch with –2V Undershoot Protection

General Description

The Fairchild Switch FSTU16862 provides 20-bits of highspeed CMOS TTL-compatible bus switching. The low On Resistance of the switch allows inputs to be connected to outputs without adding propagation delay or generating additional ground bounce noise.

The device is organized as a 20-bit bus switch. When \overline{OE}_X is LOW, the switch is ON and Port A is connected to Port B. When \overline{OE}_X is HIGH, a high impedance state exists between the A and B Ports. The A and B Ports are protected against undershoot to support an extended range to 2.0V below ground. Fairchild's integrated Undershoot Hardened Circuit (UHCTM) senses undershoot at the I/O and responds by preventing voltage differentials from developing and turning the switch on.

Features

- Undershoot hardened to -2V (A and B Ports)
- \blacksquare 4 Ω switch connection between two ports
- Minimal propagation delay through the switch
- Low I_{CC}
- Zero bounce in flow-through mode
- Control inputs compatible with TTL level
- See Application Note AN-5008 for details on FSTU - Undershoot Protected Fairchild Switch Family

Ordering Code:

Order Number	Package Number	Package Description
FSTU16862QSP	MQA48A	48-Lead Quarter Size Very Small Outline Package (QVSOP), JEDEC MO-154, 0.150" Wide
FSTU16862MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

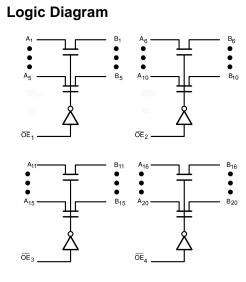
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

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FSTU16862



Pin Descriptions

Pin Name	Description
OEx	Bus Switch Enables
A	Bus A
В	Bus B

Truth Table

Inputs	Inputs/Outputs
OE _x	А, В
L	A = B
Н	Z

H = HIGH Voltage Level L = LOW Voltage Level Z = High Impedance

Connection Diagram ₀e2. 48 Vcc A1 47 OE1 2 46 в1 A₂ A₃ 45 B₂ A₄ B₃ 44 A_5 43 B⊿ A₆ 42 B5 A7 41 -B₆ A₈ 40 9 -B7 10

Ag	10	39	— ^B 8
A ₁₀ —	11	38	— B9
GND	12	37	- B ₁₀
ōe ₄ —	13	36	- v _{cc}
A ₁₁ —	14	35	- OE3
A ₁₂	15	34	-B ₁₁
A ₁₃ —	16	33	B ₁₂
A ₁₄ —	17	32	— ^B 13
A ₁₅ —	18	31	— ^В 14
A ₁₆ —	19	30	B ₁₅
A17 -	20	29	-B ₁₆
A ₁₈ —	21	28	B ₁₇
A ₁₉ —	22	27	-B ₁₈
A ₂₀	23	26	-B ₁₉
GND	24	25	-B ₂₀

Absolute Maximum Ratings(Note 1)

Supply Voltage (V _{CC})	-0.5V to +7.0V
DC Switch Voltage (V_S) (Note 2)	-2.0V to +7.0V
DC Input Voltage (V _{IN}) (Note 3)	-0.5V to +7.0V
DC Input Diode Current (I _{IK}) V _{IN} < 0V	–50 mA
DC Output Current (I _{OUT})	128 mA
DC V _{CC} /GND Current (I _{CC} /I _{GND})	±100 mA
Storage Temperature Range (T _{STG})	-65°C to +150 °C

Recommended Operating Conditions (Note 4)

Conditions (Note 4)	
Power Supply Operating $(V_{CC)}$	4.0V to 5.5V
Input Voltage (V _{IN})	0V to 5.5V
Output Voltage (V _{OUT})	0V to 5.5V
Input Rise and Fall Time (t_r, t_f)	
Switch Control Input	0 ns/V to 5 ns/V
Switch I/O	0 ns/V to DC
Free Air Operating Temperature (T _A)	-40 °C to +85 °C

FSTU16862

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum rating. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: V_S is the voltage observed/applied at either the A or B Ports across the switch.

Note 3: The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed.

Note 4: Unused control inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

	Parameter	V _{CC}	Τ _Α	=-40 °C to +8	5 °C		
Symbol		(V)	Min	Typ (Note 5)	Max	Units	Conditions
VIK	Clamp Diode Voltage	4.5			-1.2	V	I _{IN} = -18 mA
VIH	HIGH Level Input Voltage	4.0-5.5	2.0			V	
VIL	LOW Level Input Voltage	4.0-5.5			0.8	V	
l _l	Input Leakage Current	5.5			±1.0	μA	$0 \le V_{IN} \le 5.5 V$
		0			10	μA	$V_{IN} = 5.5V$
I _{OZ}	OFF-STATE Leakage Current	5.5			±1.0	μA	$0 \le A, B \le V_{CC}$
R _{ON}	Switch On Resistance	4.5		4	7	Ω	$V_{IN} = 0V$, $I_{IN} = 64 \text{ mA}$
	(Note 6)	4.5		4	7	Ω	$V_{IN} = 0V, I_{IN} = 30 \text{ mA}$
		4.5		8	14	Ω	$V_{IN} = 2.4V, I_{IN} = 15 \text{ mA}$
		4.0		11	20	Ω	$V_{IN} = 2.4V, I_{IN} = 15 \text{ mA}$
I _{CC}	Quiescent Supply Current	5.5			3	μA	$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0$
ΔI_{CC}	Increase in I _{CC} per Input	5.5			2.5	mA	One Input at 3.4V
	(Note 7)						Other Inputs at V_{CC} or GND
V _{IKU}	Voltage Undershoot	5.5			-2.0	V	$0.0~mA \ge I_{IN} \ge -50~mA$
							<u>OE</u> = 5.5V

Note 5: Typical values are at V_{CC} = 5.0V and T_A = +25 $^{\circ}C$

Note 6: Measured by the voltage drop between A and B pins at the indicated current through the switch. On Resistance is determined by the lower of the voltages on the two (A or B) pins.

Note 7: Per TTL driven input, control pins only.

FSTU16862

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40$ °C to +85 °C, $C_L = 50$ pF, RU = RD = 500 Ω				Units	Conditions	Figure	
Cymber	i arameter	V _{CC} = 4.	.5 – 5.5V	Vcc	= 4.0V	01110	Conditions	Number	
		Min	Max	Min	Max				
t _{PHL} , t _{PLH}	Propagation Delay Bus-to-Bus (Note 8)		0.25		0.25	ns	V _I = OPEN	Figures 2, 3	
t _{PZH} , t _{PZL}	Output Enable Time	1.0	5.9		6.4	ns	$V_I = 7V$ for t_{PZL} $V_I = OPEN$ for t_{PZH}	Figures 2, 3	
t _{PHZ} , t _{PLZ}	Output Disable Time	1.0	6.9		7.4	ns	$V_I = 7V$ for t_{PLZ} $V_I = OPEN$ for t_{PHZ}	Figures 2, 3	

Note 8: This parameter is guaranteed by design but is not tested. The bus switch contributes no propagation delay other than the RC delay of the typical On Resistance of the switch and the 50pF load capacitance, when driven by an ideal voltage source (zero output impedance).

Capacitance (Note 9)

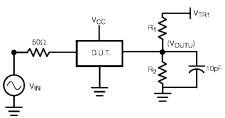
Symbol	Parameter	Тур	Max	Units	Conditions
C _{IN}	Control Pin Input Capacitance	3		pF	$V_{CC} = 5.0V, V_{IN} = 0V$
C _{I/O}	Input/Output Capacitance "OFF State"	6		pF	$V_{CC}, \overline{OE} = 5.0V, V_{IN} = 0V$

Note 9: $T_A = +25^{\circ}C$, f = 1 MHz, Capacitance is characterized but not tested.

Undershoot Characteristic (Note 10)

Symbol	Parameter	Min	Тур	Max	Units	Conditions
V _{OUTU}	Output Voltage During Undershoot	2.5	V _{OH} - 0.3		V	Figure 1
Note 10: This test is intended to characterize the device's protective conshilities by maintaining output signal integrity during an input transient voltage						

Note 10: This test is intended to characterize the device's protective capabilities by maintaining output signal integrity during an input transient voltage undershoot event.

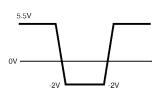




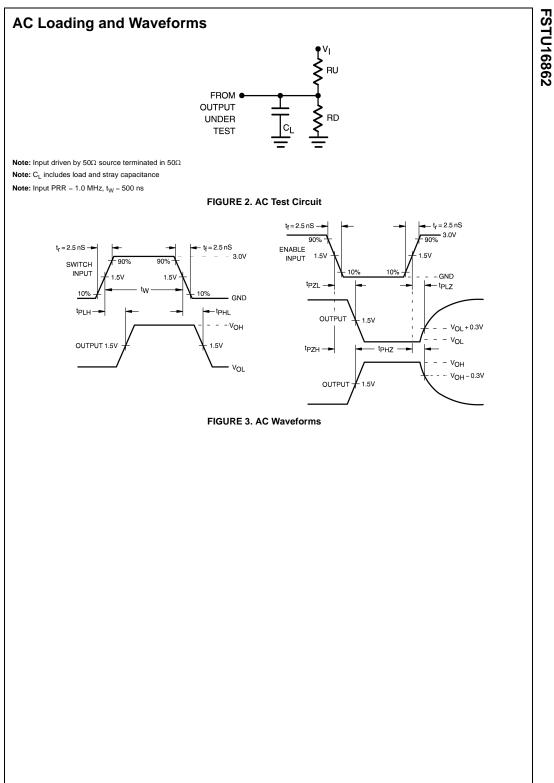
Device Test Conditions

Parameter	Value	Units
V _{IN}	see Waveform	V
$R_1 = R_2$	100K	Ω
V _{TRI}	11.0	V
V _{CC}	5.5	V

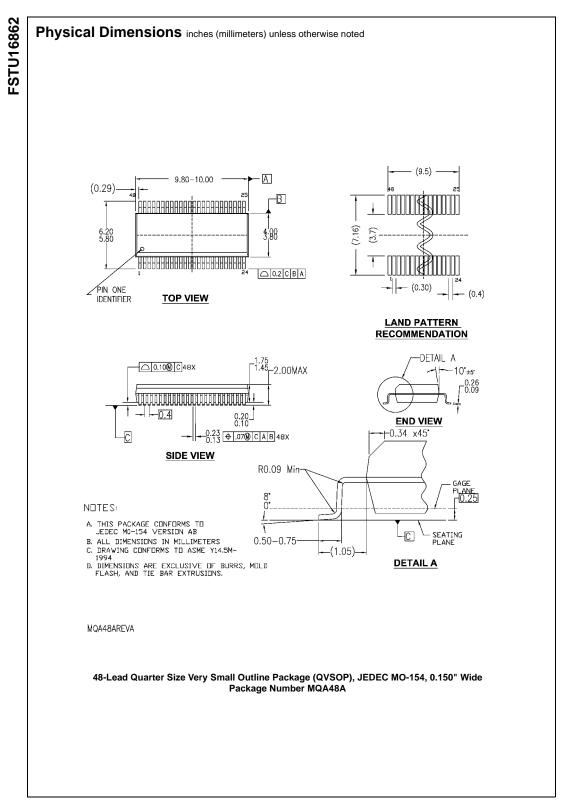
Transient Input Voltage (V_{IN}) Waveform



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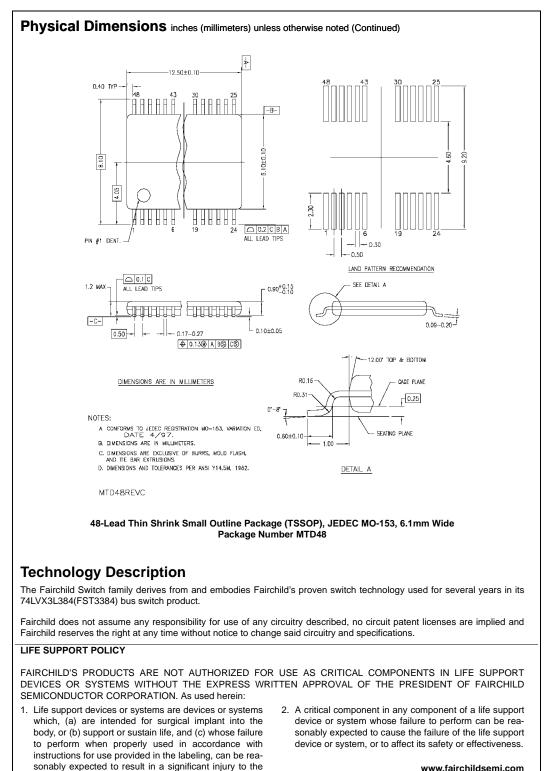


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